# 74AHC1G02; 74AHCT1G02

2-input NOR gate
Rev. 7 — 6 November 2014

Product data sheet

#### 1. **General description**

74AHC1G02 and 74AHCT1G02 are high-speed Si-gate CMOS devices. They provide a 2-input NOR function.

The AHC device has CMOS input switching levels and supply voltage range 2 V to 5.5 V.

The AHCT device has TTL input switching levels and supply voltage range 4.5 V to 5.5 V.

#### 2. **Features and benefits**

- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- SOT353-1 and SOT753 package options
- ESD protection:
  - ◆ HBM JESD22-A114E: exceeds 2000 V
  - ♦ MM JESD22-A115-A: exceeds 200 V
  - ◆ CDM JESD22-C101C: exceeds 1000 V
- Specified from –40 °C to +125 °C

#### **Ordering information** 3.

Table 1. **Ordering information** 

Type number	Package									
	Temperature range	Name	Description	Version						
74AHC1G02GW	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package;	SOT353-1						
74AHCT1G02GW			5 leads; body width 1.25 mm							
74AHC1G02GV	-40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753						
74AHCT1G02GV										



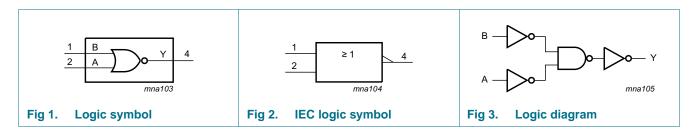
### 4. Marking

#### Table 2. Marking codes

Type number	Marking <sup>[1]</sup>
74AHC1G02GW	AB
74AHC1G02GV	A02
74AHCT1G02GW	СВ
74AHCT1G02GV	C02

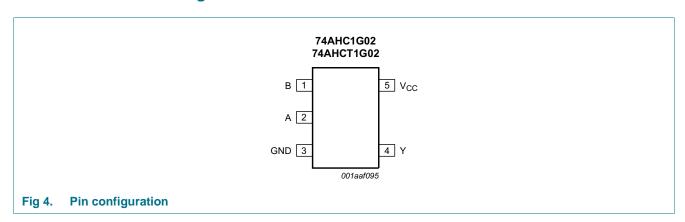
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

### 5. Functional diagram



### 6. Pinning information

### 6.1 Pinning



### 6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
В	1	data input B
Α	2	data input A
GND	3	ground (0 V)
Υ	4	data output Y
V <sub>CC</sub>	5	supply voltage

74AHC\_AHCT1G02

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### 7. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level$ 

Inputs	Output	
A	В	Υ
L	L	Н
L	Н	L
Н	L	L
Н	Н	L

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+7.0	V
VI	input voltage			-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < -0.5 V		-20	-	mA
I <sub>OK</sub>	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$	<u>[1]</u>	-	±20	mA
Io	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$		-	±25	mA
I <sub>CC</sub>	supply current			-	75	mA
I <sub>GND</sub>	ground current			-75	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$	[2]	-	250	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

# 9. Recommended operating conditions

#### Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	74	AHC1G	)2	74	Unit		
			Min	Тур	Max	Min	Тур	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	0	-	5.5	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	-	-	100	-	-	-	ns/V
	and fall rate	$V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	-	-	20	-	-	20	ns/V

<sup>[2]</sup> For both TSSOP5 and SC-74A packages: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K.

### 10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol Parameter		Conditions		25 °C		-40 °C 1	to +85 °C	-40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
For type	74AHC1G02									
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	-	-	1.5	-	1.5	-	٧
	input voltage	V <sub>CC</sub> = 3.0 V	2.1	-	-	2.1	-	2.1	-	٧
		V <sub>CC</sub> = 5.5 V	3.85	-	-	3.85	-	3.85	-	٧
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.0 V	-	-	0.5	-	0.5	-	0.5	٧
	input voltage	V <sub>CC</sub> = 3.0 V	-	-	0.9	-	0.9	-	0.9	٧
		V <sub>CC</sub> = 5.5 V	-	-	1.65	-	1.65	-	1.65	٧
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	$I_O = -50 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	٧
		$I_O = -50 \mu A; V_{CC} = 3.0 \text{ V}$	2.9	3.0	-	2.9	-	2.9	-	٧
		$I_O = -50 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	٧
		$I_O = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.58	-	-	2.48	-	2.40	-	٧
		$I_{O} = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.94	-	-	3.8	-	3.70	-	٧
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	$I_O = 50 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	٧
		$I_O = 50 \mu A; V_{CC} = 3.0 \text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 50 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	-	0.44	-	0.55	٧
		$I_O = 8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.36	-	0.44	-	0.55	٧
l <sub>l</sub>	input leakage current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μА
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	1.0	-	10	-	40	μΑ
Cı	input capacitance		-	1.5	10	-	10	-	10	pF
For type	74AHCT1G02									
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	-	-	2.0	-	2.0	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	0.8	-	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = -50 μA	4.4	4.5	-	4.4	-	4.4	-	٧
		$I_{O} = -8.0 \text{ mA}$	3.94	-	-	3.8	-	3.70	-	٧
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = 50 μA	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 8.0 mA	-	-	0.36	-	0.44	-	0.55	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μА

74AHC\_AHCT1G02

 Table 7.
 Static characteristics ...continued

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C 1	to +85 °C	–40 °C t	Unit	
			Min	Тур	Max	Min	Max	Min	Max	
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	1.0	-	10	-	40	μΑ
$\Delta I_{CC}$	additional supply current	per input pin; $V_I = 3.4 \text{ V}$ ; other inputs at $V_{CC}$ or GND; $I_O = 0 \text{ A}$ ; $V_{CC} = 5.5 \text{ V}$	-	-	1.35	-	1.5	-	1.5	mA
Cı	input capacitance		-	1.5	10	-	10	-	10	pF

### 11. Dynamic characteristics

#### Table 8. Dynamic characteristics

GND = 0 V;  $t_r = t_f = \le 3.0$  ns. For test circuit see <u>Figure 6</u>.

Symbol	Parameter	Conditions			25 °C		-40 °C	to +85 °C	-40 °C t	o +125 °C	Unit
					Тур	Max	Min	Max	Min	Max	
For type	74AHC1G02										
t <sub>pd</sub>	propagation	A and B to Y; see Figure 5	[1]								
	delay	V <sub>CC</sub> = 3.0 V to 3.6 V	[2]								
		C <sub>L</sub> = 15 pF		-	4.4	7.9	1.0	9.5	1.0	10.5	ns
		C <sub>L</sub> = 50 pF		-	6.3	11.4	1.0	13	1.0	14.5	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[3]								
		C <sub>L</sub> = 15 pF		-	3.2	5.5	1.0	6.5	1.0	7.0	ns
		C <sub>L</sub> = 50 pF		-	4.6	7.5	1.0	8.5	1.0	9.5	ns
C <sub>PD</sub>	power dissipation capacitance	per buffer; [4] C <sub>L</sub> = 50 pF; f = 1 MHz; V <sub>I</sub> = GND to V <sub>CC</sub>		-	18	-	-	-	-	-	pF
For type	74AHCT1G02	2					1		1	1	
t <sub>pd</sub>	propagation	A and B to Y; see Figure 5	[1]								
	delay	V <sub>CC</sub> = 4.5 V to 5.5 V	[3]								
		C <sub>L</sub> = 15 pF		-	3.5	5.5	1.0	6.5	1.0	7.0	ns
		C <sub>L</sub> = 50 pF		-	4.9	7.5	1.0	8.5	1.0	9.5	ns
C <sub>PD</sub>	power dissipation capacitance	per buffer; $C_L = 50 \text{ pF}$ ; $f = 1 \text{ MHz}$ ; $V_I = \text{GND to } V_{CC}$	[4]	-	19	-	-	-	-	-	pF

- [1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .
- [2] Typical values are measured at  $V_{CC}$  = 3.3 V.
- [3] Typical values are measured at  $V_{CC} = 5.0 \text{ V}$ .
- [4]  $C_{PD}$  is used to determine the dynamic power dissipation  $P_D$  ( $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}{}^2 \times f_i + \sum{(C_L \times V_{CC}{}^2 \times f_o)}$  where:

 $f_i$  = input frequency in MHz;  $f_o$  = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in Volts.

74AHC\_AHCT1G02

### 12. Waveforms

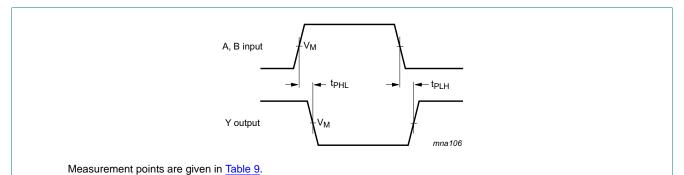
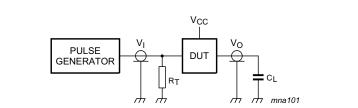


Fig 5. The inputs (A and B) to output (Y) propagation delays

#### Table 9. Measurement point

Туре	Input	Output	
	V <sub>I</sub>	V <sub>M</sub>	V <sub>M</sub>
74AHC1G02	GND to V <sub>CC</sub>	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
74AHCT1G02	GND to 3.0 V	1.5 V	$0.5 \times V_{CC}$



Test data is given in Table 8. Definitions for test circuit:

 $C_L$  = Load capacitance including jig and probe capacitance.

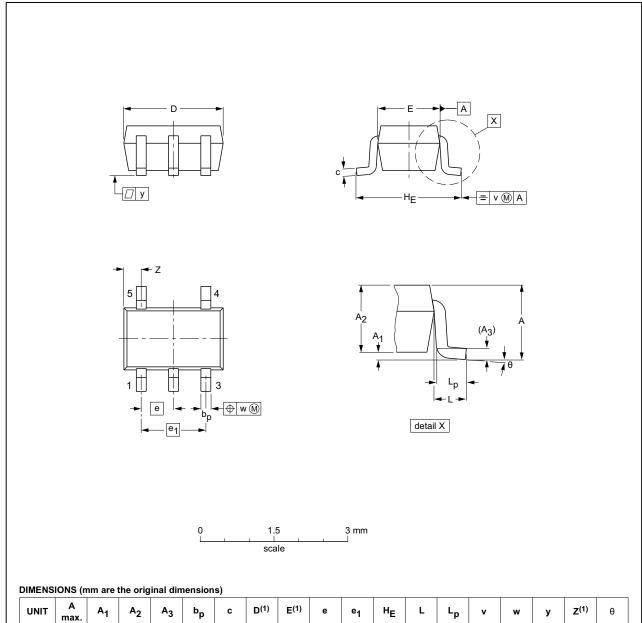
 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

Fig 6. Test circuit for measuring switching times

### 13. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



UNIT	max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D(1)	E <sup>(1)</sup>	е	e <sub>1</sub>	HE	L	Lp	v	w	у	Z <sup>(1)</sup>	θ
mm	1.1	0.1 0	1.0 0.8	0.15	0.30 0.15	0.25 0.08	2.25 1.85	1.35 1.15	0.65	1.3	2.25 2.0	0.425	0.46 0.21	0.3	0.1	0.1	0.60 0.15	7° 0°

#### Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	RSION		JEITA		PROJECTION	ISSUE DATE
SOT353-1		MO-203	SC-88A			<del>00-09-01</del> 03-02-19

Fig 7. Package outline SOT353-1 (TSSOP5)

74AHC\_AHCT1G02

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#### **SOT753** Plastic surface-mounted package; 5 leads В Α X = v (M) A $H_{\mathsf{E}}$ 5 Q 3 detail X **→** | w (M) B е scale **DIMENSIONS** (mm are the original dimensions) UNIT D Q Α С Е $A_1$ bp е ΗE $L_{\mathbf{p}}$ w у 0.100 0.40 3.0 2.5 0.26 3.1 2.7 1.1 1.7 0.6 0.33 0.95 0.1 0.013 0.25 0.9 0.10 1.3 0.23 0.2 REFERENCES **EUROPEAN** OUTLINE ISSUE DATE VERSION JEDEC **PROJECTION** IEC **JEITA** 02-04-16 SOT753 SC-74A 06-03-16

Fig 8. Package outline SOT753 (SC-74A)

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### 14. Abbreviations

#### Table 10. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

## 15. Revision history

### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74AHC_AHCT1G02 v.7	20141106	Product data sheet	-	74AHC_AHCT1G02 v.6	
Modifications:	Section 4: table note added.				
74AHC_AHCT1G02 v.6	20070530	Product data sheet	-	74AHC_AHCT1G02 v.5	
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> </ul>				
	<ul> <li>Legal texts</li> </ul>	have been adapted to the new	company name	where appropriate.	
	<ul> <li>Package S</li> </ul>	OT353 changed to SOT353-1	in <u>Section 3</u> and <u>S</u>	Section 13.	
	Quick reference data and Soldering sections removed.				
74AHC_AHCT1G02 v.5	20020527	Product specification	-	74AHC_AHCT1G02 v.4	
74AHC_AHCT1G02 v.4	20020215	Product specification	-	74AHC_AHCT1G02 v.3	
74AHC_AHCT1G02 v.3	20010131	Product specification	-	74AHC_AHCT1G02 v.2	
74AHC_AHCT1G02 v.2	19990127	Product specification	-	74AHC_AHCT1G02_N v.1	
74AHC_AHCT1G02_N v.1	19981125	Preliminary specification	-	-	

### 16. Legal information

#### 16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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74AHC\_AHCT1G02

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# 74AHC1G02; 74AHCT1G02

2-input NOR gate

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### 18. Contents

1	General description
2	Features and benefits
3	Ordering information 1
4	Marking 2
5	Functional diagram 2
6	Pinning information
6.1	Pinning
6.2	Pin description 2
7	Functional description 3
8	Limiting values 3
9	Recommended operating conditions 3
10	Static characteristics 4
11	Dynamic characteristics 5
12	Waveforms 6
13	Package outline
14	Abbreviations9
15	Revision history9
16	Legal information
16.1	Data sheet status
16.2	Definitions
16.3	Disclaimers
16.4	Trademarks11
17	Contact information 11
18	Contents

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